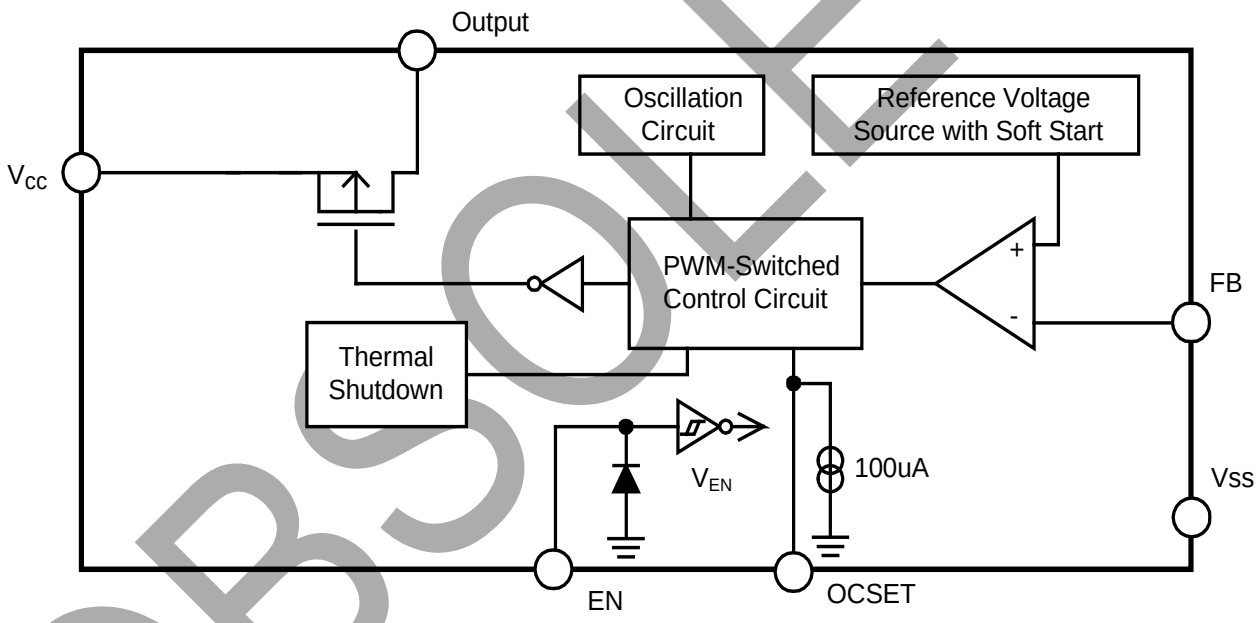
Pin Descriptions

Pin Number	Pin Name	Description
1	FB	Feedback pin
2	EN	Enable Input pin H: Normal operation (Step-down operation) L: Step-down operation stopped (All circuits deactivated)
3	OCSET	Add an external resistor to set max output current
4	V_{CC}	IC power supply pin
5, 6	Output	Switch Pin. Connect external inductor/diode here. Minimize trace area at this pin to reduce EMI
7, 8	V_{SS}	GND Pin

Functional Block Diagram



Absolute Maximum Ratings

Symbol	Parameter	Rating	Unit
V_{CC}	V_{CC} Pin Voltage	V_{SS} - 0.3 to V_{SS} + 25	V
V_{FB}	FB Pin Voltage	V_{SS} - 0.3 to V_{CC}	V
V_{EN}	EN Pin Voltage	V_{SS} - 0.3 to V_{IN} + 0.3	V
V_{OUT}	Output Pin Voltage	V_{SS} - 0.3 to V_{IN} + 0.3	V
P_D	Power Dissipation	Internally limited	mW
T_{OP}	Operating Junction Temperature Range	-20 to +125	°C
T_{ST}	Storage Temperature Range	-65 to +150	°C

Caution: The absolute maximum ratings are rated values exceeding which the product could suffer physical damage. These values must therefore not be exceeded under any conditions.

Recommended Operating Conditions

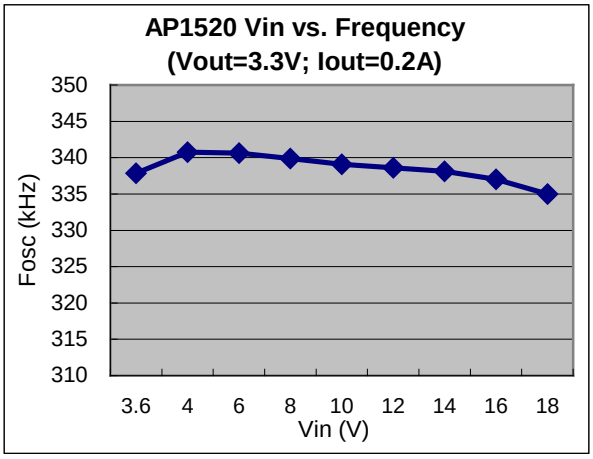
Symbol	Parameter	Min	Max	Unit
V_{IN}	Input Voltage	3.6	23	V
I_{OUT}	Output Current	0	1.8	A
T_A	Operating Ambient Temperature	-25	+85	°C

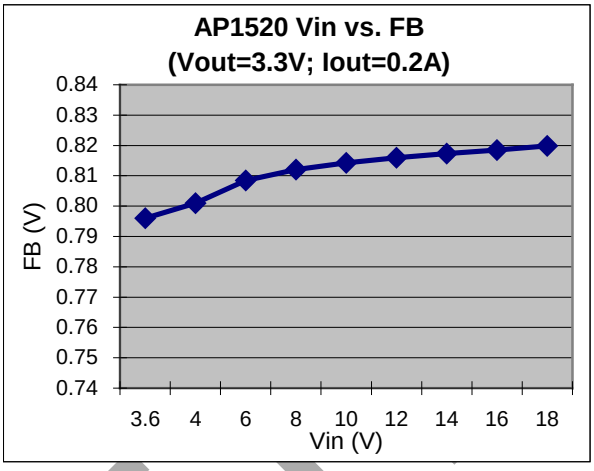
Electrical Characteristics (V_{IN} = 12V, T_A = +25°C, unless otherwise specified.)

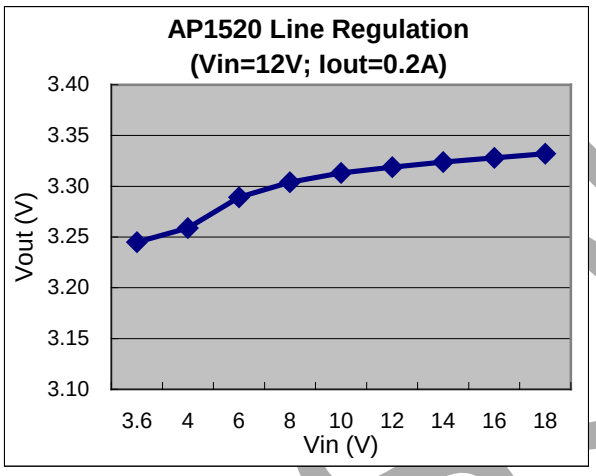
Symbol	Parameter	Conditions	Min	Typ	Max	Unit
V_{FB}	Feedback Voltage	I_{OUT} = 0.1A	0.784	0.8	0.816	V
I_{FB}	Feedback Bias Current	I_{OUT} = 0.1A	—	0.1	0.5	μA
I_{SW}	Switch Current	—	2.5	—	—	A
I_{SHDN}	Current Consumption During Power off	V_{EN} = 0V	—	10	—	μA
ΔV_{OUT} /V_{IN}	Line Regulation	V_{IN} = 5V to 23V	—	1	2	%
ΔV_{OUT} /V_{OUT}	Load Regulation	I_{OUT} = 0.1 to 2A	—	0.2	0.5	%
f_{OSC}	Oscillation Frequency	Measure waveform at Output pin	240	300	360	kHz
f_{OSC1}	Frequency of Current Limit or Short Circuit Protection	Measure waveform at Output pin	10	—	—	kHz
V_{IH}	EN Pin Input Voltage	Evaluate oscillation at Output pin	2.0	—	—	V
V_{IL}		Evaluate oscillation stop at Output pin	—	—	0.8	
I_{ENH}	EN Pin Input Leakage Current	—	—	20	—	μA
I_{ENL}		—	—	-10	—	μA
I_{OCSET}	OCSET Pin Bias Current	—	75	90	105	μA
t_{SS}	Soft-Start Time	—	0.3	1	2	ms
T_{SHDN}	Thermal Shutdown Threshold	—	—	+150	—	°C
T_{HYS}	Thermal Shutdown Hysteresis	—	—	+55	—	°C
R_{DSON}	Internal MOSFET R_{DSON}	V_{IN} = 5V, V_{FB} = 0V	—	110	150	mΩ
		V_{IN} = 12V, V_{FB} = 0V	—	70	100	
EFFI	Efficiency	V_{IN} = 12V, V_{OUT} = 5V I_{OUT} = 2A	—	92	—	%
θ_{JA}	Thermal Resistance Junction-to-Ambient	SO-8 (Note 4)	—	134	—	°C/W
θ_{JC}	Thermal Resistance Junction-to-Case	SO-8 (Note 4)	—	22	—	°C/W

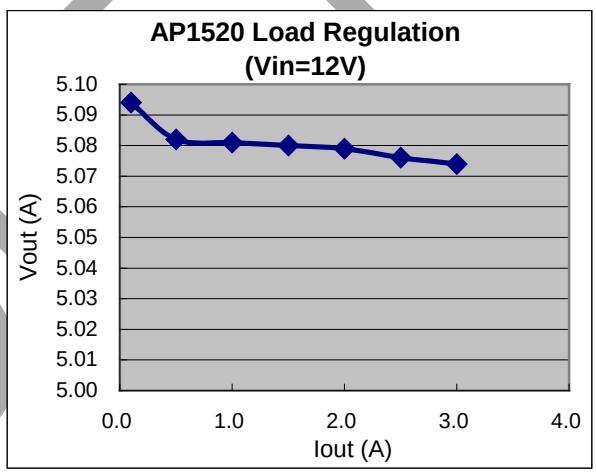
Note: 4. Test condition: Device mounted on FR-4 substrate 2oz copper, minimum recommended pad layout, single side. For better thermal performance, please arrange larger copper pad of layout for heatsink.

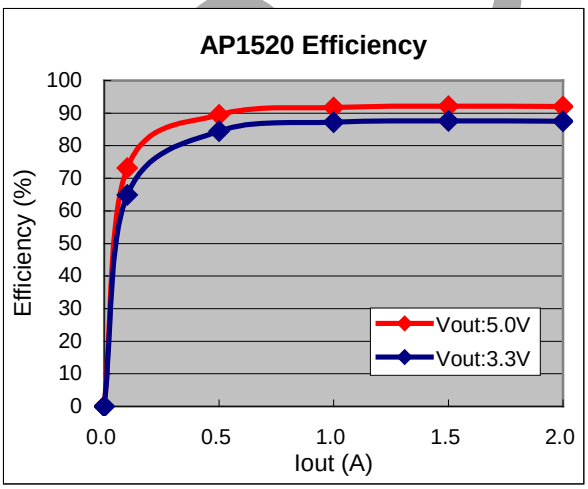
Performance Characteristics





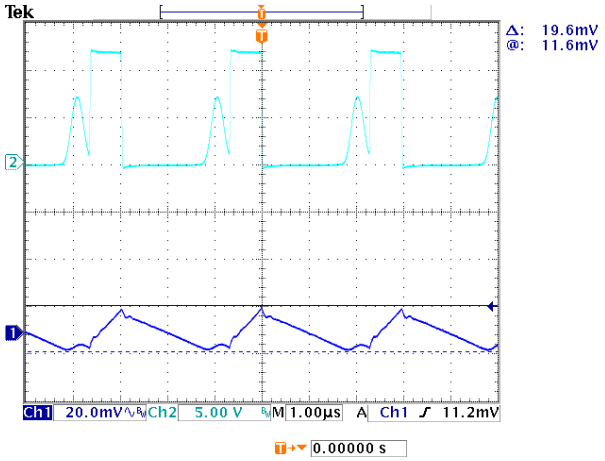




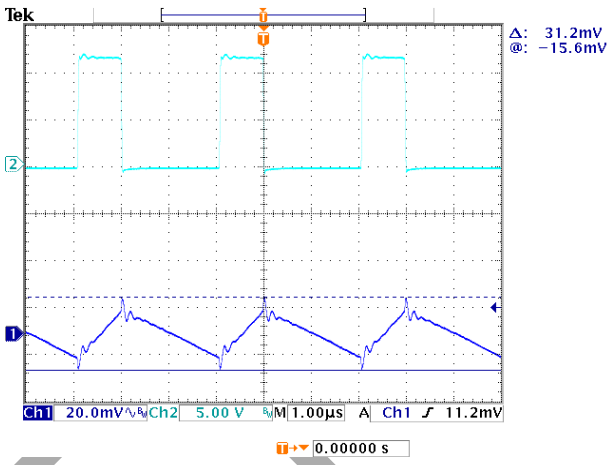


Performance Characteristics (Cont.)

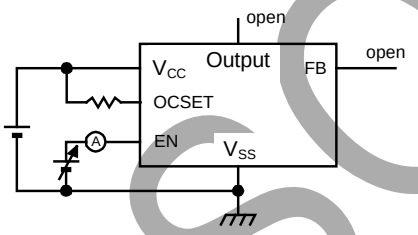
AP1520 Vout Ripple
(V_{in} = 12V; V_{out} = 3.3V; I_{out} = 0.1A)



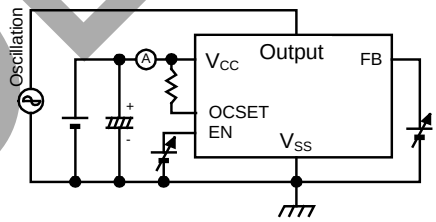
AP1520 Vout Ripple
(V_{in} = 12V; V_{out} = 3.3V; I_{out} = 2A)



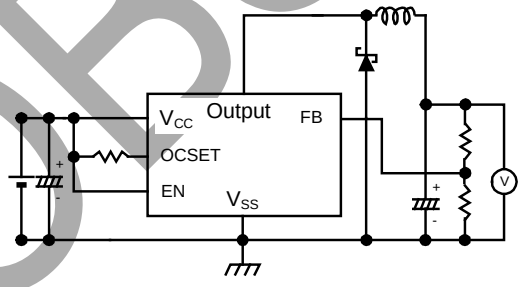
Test Circuit



Enable function test



Feedback function test



Operation function test

Functional Description

PWM Control

The AP1520 is a DC/DC converter that employs pulse width modulation (PWM) scheme. Its pulse width varies in the range of 0% to 99%, based on the output current loading. The output ripple voltage caused by the PWM high frequency switching can easily be reduced through an output filter. Therefore, this converter provides a low ripple output supply over a broad range of input voltage & output current loading.

Under Voltage Lockout

The under voltage lockout circuit of the AP1520 assures that the high-side MOSFET driver remains in the off state whenever the supply voltage drops below 3.3V. Normal operation resumes once V_{CC} rises above 3.5V.

Current Limit Protection

The current limit threshold is set by external resistor R_{OCSET} connected from V_{CC} supply to OCSET pin. The internal sink current I_{OCSET} (90μA typical) across this resistor sets the voltage at OCSET pin. When the PWM voltage is less than the voltage at OCSET, an over-current condition is triggered.

The current limit threshold is given by the following equation:

$$I_{PEAK} \times R_{DS(ON)} = I_{OCSET} \times R_{OCSET}$$

$$I_{PEAK} > I_{OUT(MAX)} + \frac{(\Delta I)}{2}$$

where,

$$\Delta I = \frac{V_{IN} - V_{OUT}}{fs \times L} \times \frac{V_{OUT}}{V_{IN}}$$

I_{PEAK} is the output peak current; $R_{DS(ON)}$ is the MOSFET ON resistance; f_S is the PWM frequency (300kHz typical). Also, the inductor value will affect the ripple current ΔI.

The above equation is recommended for input voltage range of 5V to 18V. For input voltage lower than 5V or ambient temperature over +100°C, higher R_{OCSET} is recommended.

Inductor Selection

For most designs, the operation range with inductors is from 22μH to 33μH. The inductor value can be derived from the following equation:

$$L = \frac{V_{IN} - V_{OUT}}{fs \times \Delta I} \times \frac{V_{OUT}}{V_{IN}}$$

Where ΔI_L is inductor Ripple Current. Large value inductors lower ripple current and small value inductors result in high ripple current. Choose inductor ripple current approximately 15% of the maximum load current 2A, ΔI_L=0.30A. The DC current rating of the inductor should be at least equal to the maximum load current plus half the ripple current to prevent core saturation (2A+0.15A).

Input Capacitor Selection

This capacitor should be located close to the IC using short leads and the voltage rating should be approximately 1.5 times the maximum input voltage. The RMS current rating requirement for the input capacitor of a buck regulator is approximately ½ the DC load current. A low ESR input capacitor sized for maximum RMS current must be used. A 470μF low ESR capacitor for most applications is sufficient.

Output Capacitor Selection

The output capacitor is required to filter the output voltage and provides regulator loop stability. The important capacitor parameters are the 100kHz Equivalent Series Resistance (ESR), the RMS ripples current rating, voltage rating and capacitance value. For the output capacitor, the ESR value is the most important parameter. The output ripple can be calculated from the following formula.

Functional Description (Cont.)

$$V_{RIPPLE} = \Delta I_L \times ESR$$

The bulk capacitor's ESR will determine the output ripple voltage and the initial voltage drop after a high slew-rate transient.

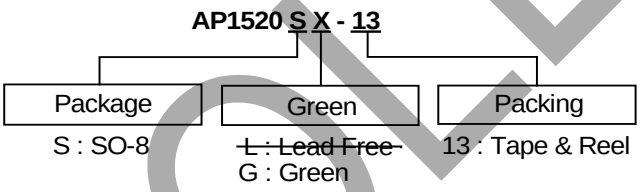
An aluminum electrolytic capacitor's ESR value is related to the capacitance and its voltage rating. In most case, higher voltage electrolytic capacitors have lower ESR values. Most of the time, capacitors with much higher voltage ratings may be needed to provide the low ESR values required for low output ripple voltage.

PCB Layout Guide

If you need low T_C & T_J or large P_D (Power Dissipation), the dual Output pins (5 & 6) and V_{SS} pins (7 & 8) on the SO-8 package are internally connected to die pad, the evaluation board should be allowed for maximum copper area at output pins.

1. Connect FB circuits as closely as possible and keep away from inductor flux for pure V_{FB}.
2. Connect input capacitor to V_{CC} and V_{SS} pin as closely as possible to get good power filter effect.
3. Connect R_{OCSET} to V_{CC} and OCSET pin as closely as possible.
4. Connect ground side of the input capacitor & Schottky & output capacitor as closely as possible and use ground plane for best performance.

Ordering Information

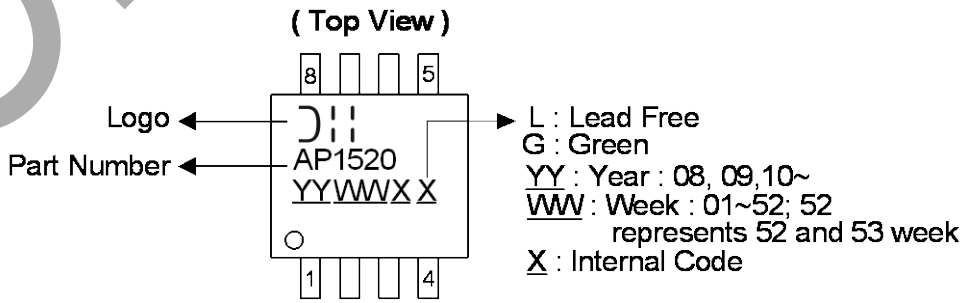


Part Number (Note 5)	Package Code	Package (Note 6)	Green	Quantity	Part Number Suffix		Status (Note 5)
					Tube	13"Tape and reel	
AP1520SG-13	S	SO-8	Green	2500	NA	-13	In production

Notes: 5. All Lead-Free variants are End of life without replacement.
6. For packaging details, go to our website at: https://www.diodes.com/design/support/packaging/diodes-packaging/diodes-package-outlines-and-pad-layouts/

Marking Information (Note 5)

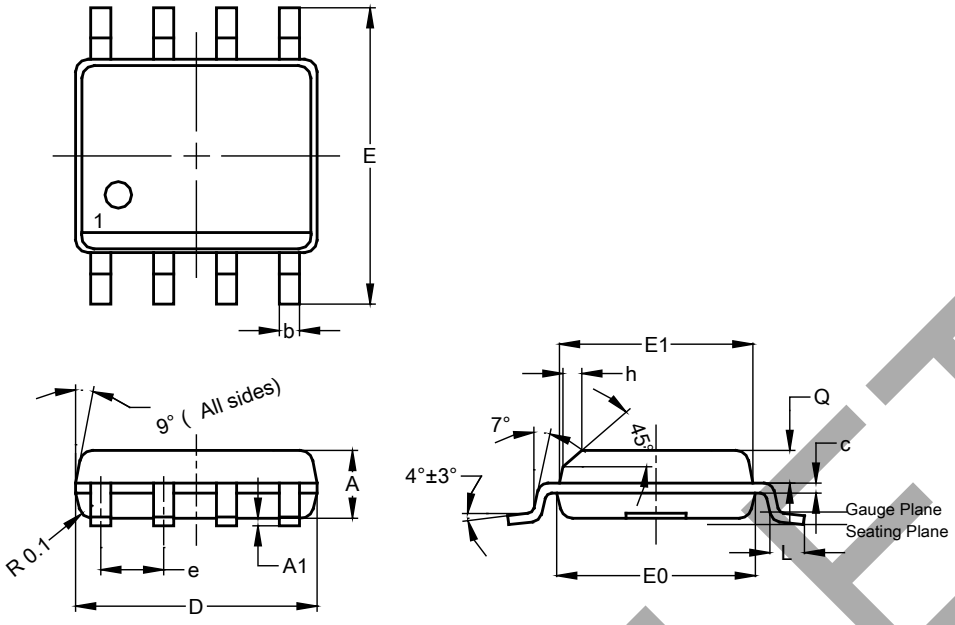
(1) SO-8



Package Outline Dimensions

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8

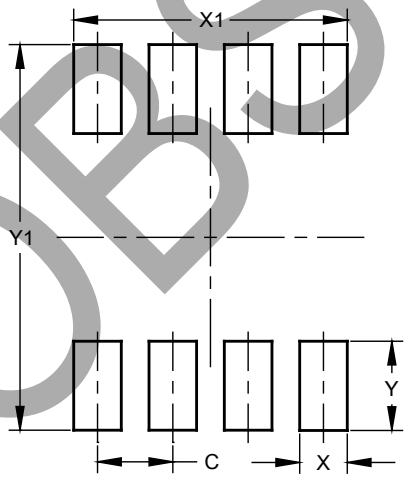


SO-8			
Dim	**Min**	**Max**	**Typ**
A	1.40	1.50	1.45
A1	0.10	0.20	0.15
b	0.30	0.50	0.40
c	0.15	0.25	0.20
D	4.85	4.95	4.90
E	5.90	6.10	6.00
E1	3.80	3.90	3.85
E0	3.85	3.95	3.90
e	--	--	1.27
h	-	--	0.35
L	0.62	0.82	0.72
Q	0.60	0.70	0.65
All Dimensions in mm			

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.

SO-8



Dimensions	Value (in mm)
C	1.27
X	0.802
X1	4.612
Y	1.505
Y1	6.50

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